

Electron Source Perspectives for C^3

(at least one person's view)

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Workshop on Future US Colliders, SLAC Jan. 2022

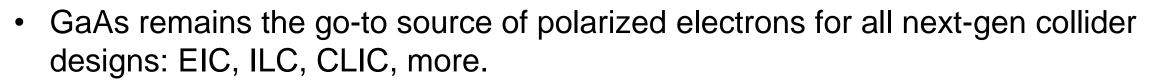




• Photocathode materials for polarized electrons.

- What is the right polarized electron gun for C^3 ?
 - DC guns past and future
 - A very high field cryogenic RF photoinjector
- Future directions





GaAs, still!

• But there have been several advancements since its inception.

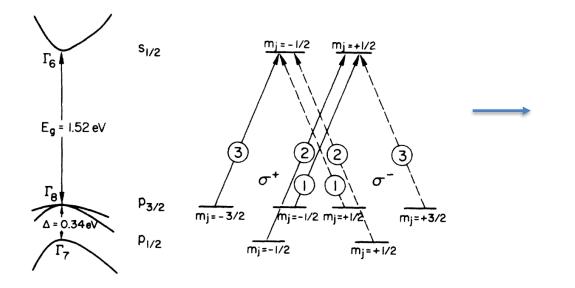
PHYSICAL REVIEW B

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15 JUNE 1976

Photoemission of spin-polarized electrons from GaAs

Daniel T. Pierce* and Felix Meier Laboratorium für Festkörperphysik, Eidgenössische Technische Hochschule, CH 8049, Zürich, Switzerland (Received 10 February 1976)

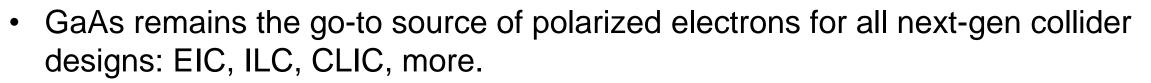


Band degeneracy: Maximum polarization of 50%.

With activation with Cs, O, bulk GaAs to yield negative electron affinity, can give QE~10% for bandgap excitation (780 nm).

Excellent intrinsic emittance at 780 nm: 0.25 um/mm rms.

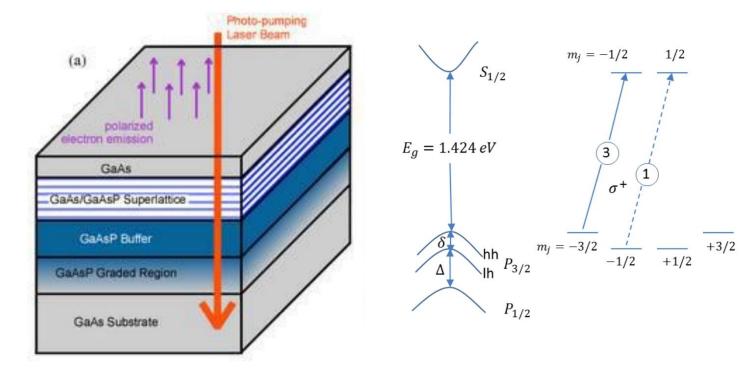




GaAs, still!

• But there have been several advancements since its inception.

Insight 1: Lift the band degeneracy with strain, ideally via a superlattice.



Very high polarization, >90% measured.

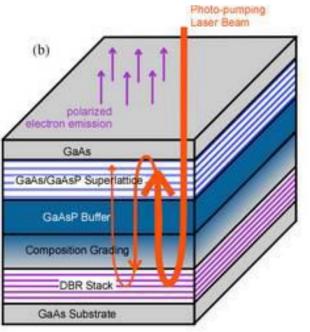
Downside: superlattice is not terribly thick—doesn't absorb much light. QE<1%

Figures from Wei Liu



- GaAs remains the go-to source of polarized electrons for all next-gen collider designs: EIC, ILC, CLIC, more.
- But there have been several advancements since its inception.

Insight 2: Engineer layer thickness and indices of refraction to engineer absorption via interferometric effects ("Distributed Bragg Reflector")



DBR photocathode

Record-level quantum efficiency from a high polarization strained GaAs/GaAsP superlattice photocathode with distributed Bragg reflector

Wei Liu,^{1,2,3,a)} Yiqiao Chen,⁴ Wentao Lu,⁴ Aaron Moy,⁴ Matthew Poelker,³ Marcy Stutzman,³ and Shukui Zhang³

QE enhanced to >6%, with polarization of 84%.

GaAs, still!

Downside? Not really! Will increase temporal response time to on the 10s of picosecond scale, but this is not important for large bunch charges.



- The main challenge with NEA GaAs photocathodes: A sub-monolayer of Cs/O activates the surface, and so a sub-monolayer of reactive gas can kill it.
- Can be rejuvenated with heating cycle and recesiation (hours).
- Operating pressures of polarized photoguns to date are typically $<10^{-11}$ torr.
- This explains an important fact: EIC, CLIC, ILC designs intend to use DC photoguns with very pure vacua.



DC guns

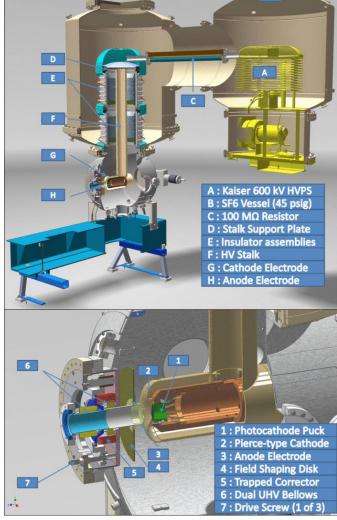
Example 1

Cornell MK-II KEK-inspired, 450 keV Tunable gap

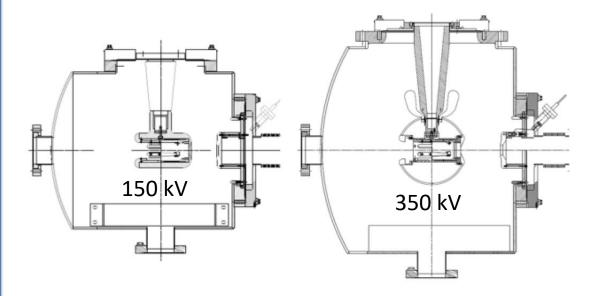
Geometry typical of highest energy designs

5 MV/m field at 450 kV.

Cathode insertion from back, not shown.







Inverted guns: simple and compact! In production at JLAB, and now BNL. Similar field, slightly lower voltage. The future!

Developed originally at SLAC: M. Breidenbach et al., NIMA, 1994.

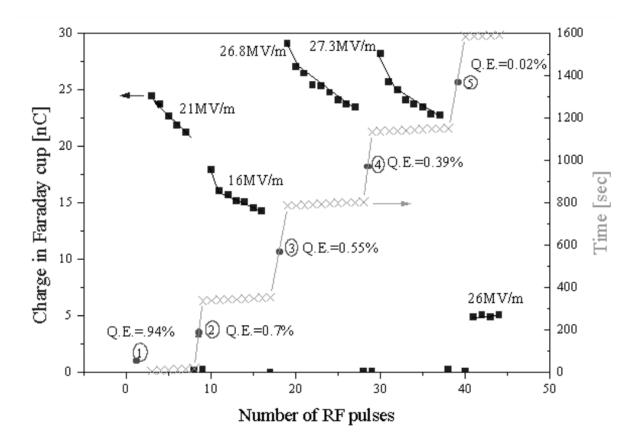


Novosibirsk RF test of GaAs

 There has been at least one test of GaAs:Cs/O in a 100 MV/m S-band RF gun:
EXPERIMENTAL STUDY OF GaAs PHOTOCATHODE

EXPERIMENTAL STUDY OF GaAs PHOTOCATHODE PERFORMANCE IN RF GUN^{*}

A.V.Aleksandrov, N.S.Dikansky, R.G.Gromov, P.V.Logatchov, BINP, Novosibirsk, Russia



- Very good base pressure considering challenging vacuum conductance of S-band guns: 2×10^{-10} torr
- Short lifetime
- Authors also note multiple orders of magnitude growth in dark current w.r.t. nominal
- Work function of NEA GaAs is only 1.6 eV (compare to ~4.4 eV for Cu).



Need for Field

- But: a strategic advantage of C³ and cryogenic copper is extreme field, ~2 orders of magnitude above DC guns.
- Transverse brightness from gun: $B_{max} \propto E_{cath}^{3/2}$
- The big source question in my mind is: Can we merge cryo-RF and polarized photoemission?
- Big opportunities:
 - greatly simplify injector
 - can even consider ultimately removing e- damping ring
- Big challenge: need to work hard on this now.



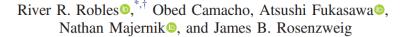
Performance of Cryo-RF gun

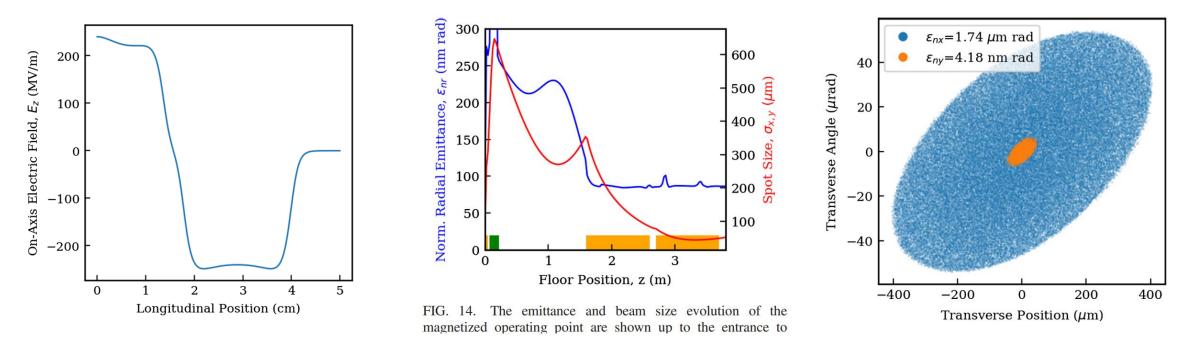
• C-band design for 100 pC, magnetized beam for asymmetric emittance.

PHYSICAL REVIEW ACCELERATORS AND BEAMS 24, 063401 (2021)



Versatile, high brightness, cryogenic photoinjector electron source

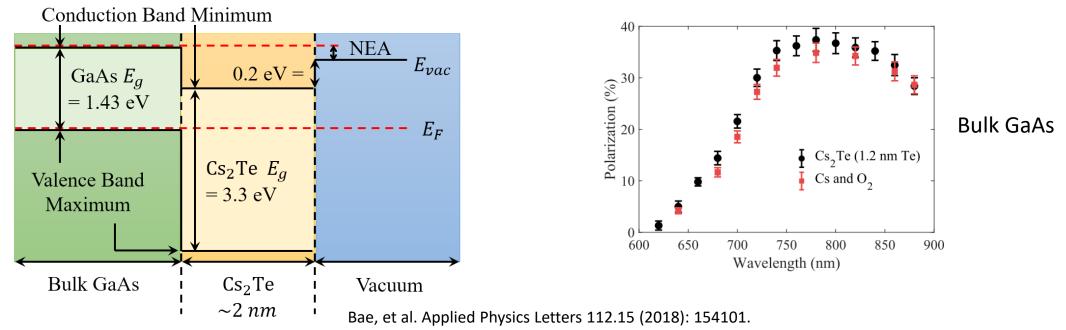




What about for 1 nC? C-band may be challenging, but an S-band source is a promising alternative



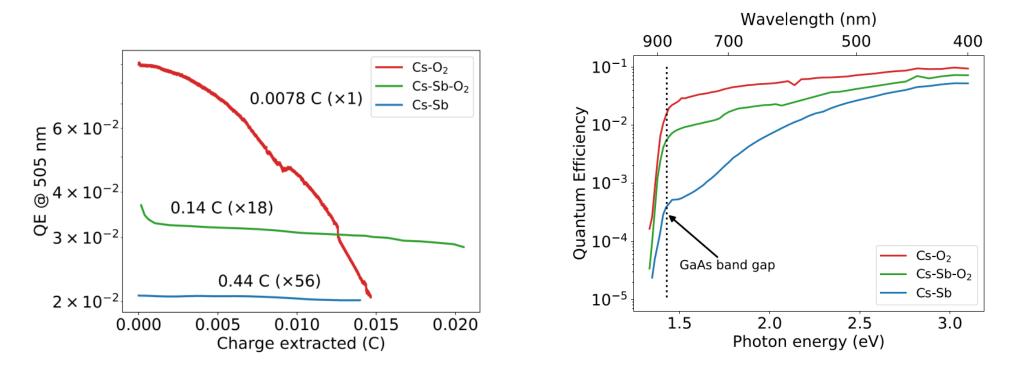
- Are there more robust activating layers?
- Uchida et al, IPAC 2014: GaAs can be activated with Cs-Te!
 - Cs-Te photocathodes are the LCLS-II baseline, regular operation at 50 MV/m in PITZ, European-XFEL, others.
- Cornell: Cs-Te activation preserves polarization and improves lifetime by at least 5x w.r.t. Cs/O.





Beyond activation with Cs/O

- Another rugged activating layer: Cs-Sb
- Orders of magnitude lifetime improvement.

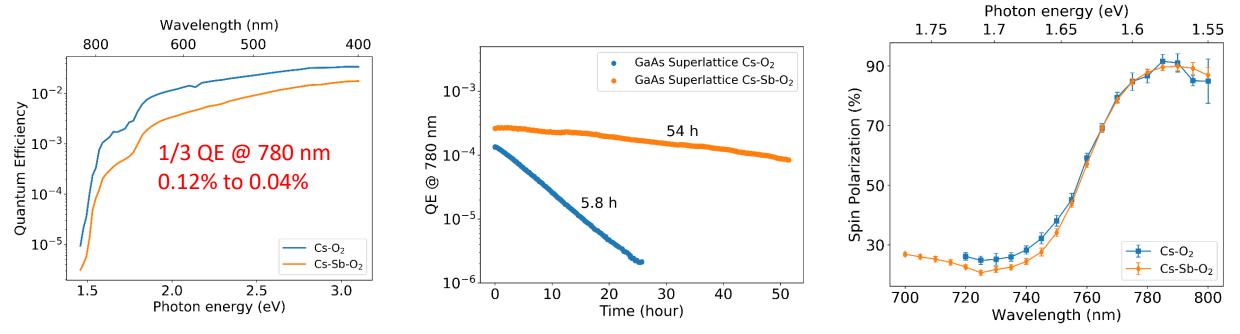


Bae et al, NAPAC 2019, MOPLH17 Bae et al, Journal of Applied Physics. **127**, 124901 (2020)



Superlattice Activation with Cs-Sb

- High polarization (90%) preserved with Cs-Sb activating layer.
- Much thicker layers provide even longer lifetime at the expense of QE and polarization.



Bae et al, Journal of Applied Physics. 127, 124901 (2020)

• Would be very interesting to try on a DBR sample (high QE)!



Looking Ahead

- Urgent need for more testing of high QE materials in RF photoguns: efforts at UCLA, LANL, PITZ, ...
- Can we look beyond GaAs? GaN (3.4 eV bandgap) is a possibility that we are currently exploring.
- More exotic coatings? Perhaps coat the activating layer with a 2-D material like Graphene or HBN? Efforts at BNL, LANL, others



Thanks!

The Cornell Polarized Photocathode Team: Jai Kwan Bae, Alice Galdi, Luca Cultrera, Matthew Andorf, Jared Maxson, Ivan Bazarov



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